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TECHNICAL REPORT BRL-TR-2845



LASER RAMAN STUDIES RELATED
TO LIQUID PROPELLANTS:
STRUCTURAL CHARACTERISTICS
INFERRED FROM THE NITRATE
ANION SPECTRA

JOHN A. VANDERHOFF STEVEN W. BUNTE PHILIP M. DONMOYER

AUGUST 1987

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I. INTRODUCTION

Candidate liquid propellants are composed of aqueous nitrate salts, the major ingredient being hydroxylammonium nitrate. The high solubility of these salts in water allows production of a liquid with sufficient energy content for use as a propellant. Moreover these concentrated salts remain a stable liquid over environmental temperatures exceeding -50 to +50°C.

Macroscopic transport properties such as viscosity and conductivity are of importance in the engineering design of a liquid propellant gun system. Since present theories cannot predict the behavior of these concentrated salt solutions, the properties must be directly measured. In the interest of advancing the understanding of the structure of solutions of HAN, as well as providing a data base, we have been performing Raman spectral measurements on HAN as a function of solute concentration. In an earlier BRL report! the experimental technique and some Raman spectra of aqueous HAN were presented. The HA+ cation, NO3 anion and H2O solvent species were all uniquely identified from their characteristic spectral signatures. This continuing study focuses on the vibrational modes of NO3 which have proven extremely useful as a spectroscopic probe of the solution structure. The interactions of the nitrate ion with its surroundings can slightly alter the normal mode vibrational frequencies and is, thus, a sensitive indica or of structural change. Correct interpretations of these vibrational va iations can provide information about macroscopic phenomena.

The nitrate ion has six normal modes of vibration, five of which are Raman active; two of these are degenerate. The ν_4 (E') degenerate mode and the ν_1 (A') symmetric stretch mode were more closely investigated to determine changes in vibrational frequencies as a function of concentration. Much of this study was performed to determine whether a case could be made for ion-pairing by analogy with published Raman spectra of other aqueous salts.

Many combinations of ions and solvent molecules with a net charge equal to zero can be envisioned, but the two simplest and most discussed forms are the contact-ion-pair and the solvent-separated-ion-pair. In the strict sense the difference between an undissociated molecule and an ion-pair is that the molecule consists of a number of atoms held together by covalent electronic bonds, whereas the ion-pair is held together entirely by electrostatic Coulomb forces and neither cation nor anion lose their identity. This definition works well for an alkali metal-halide salt. However, when applying the definition to salts such as aqueous HAN where the cation, anion, and solvent molecule can all form hydrogen bonds, the forces involved in ion-pairing can be much more complex.

In 1926, Bjerrum² defined the concept of an ion-pair in terms of an interionic distance at which the electrostatic binding energy equals 2kT. That is,

$$b = \frac{\left|z_1 z_2\right| e^2}{2\varepsilon kT} ,$$

where a cation and anion which are separated by a distance ϵ b are considered paired and longer separations considered free. z_1 and z_2 are the valences of

the cation and anion, e is the electrostatic charge, ε is the dielectric constant, k is the Boltzmann constant, and T is the absolute temperature. This is certainly a simplified approximation of ion-pairing for the case at hand; nonetheless, some qualitative trends may be determined. For instance, it is known that the dielectric constant of the solvent governs the magnitude of all electrostatic interactions, and, as will be shown, greatly influences ion-pairing. The Bjerrum equation also indicates that ion-pairing is favored as the temperature is lowered. Frost and James have observed this trend for aqueous sodium nitrate solutions, and we have made some measurements on aqueous HAN which is consistent with this trend. It is also well known experimentally that multivalent ions are more apt to ion-pair, but our discussions here will concern only monovalent ions.

II. EXPERIMENTAL

The experimental setup is essentially the same as that discussed in Ref. 1, with a few minor alterations. For the data presented here, the 514.5 nm line of an Ar laser was the source of excitation. Moderate resolution Raman spectra (6 cm FWHM) were obtained with a 1/4 m spectrograph-intensified reticon array combination. The spectrograph has a 100 micron entrance slit and a 2400 groove/mm grating. The detector in this configuration could observe about 20 nm of Raman spectra simultaneously. Data from the detector were accumulated by a computer for storage and analysis.

Nominal 13 M aqueous HAN solutions were obtained from Klein of the BRL (dilute aqueous HAN solutions were produced via electrolysis of nitric acid by Southwest Analytical Chemicals, Inc., and then concentrated by solvent stripping under vacuum) and diluted with distilled water to produce some of the less concentrated solutions used in this study. Solid HAN samples were prepared by removing the water from 13 M HAN under vacuum at room temperature. The solid formed was quickly transferred to a spectrophotometer cell and sealed with a rubber finger. At this point the solid had rough irregular surfaces. The sample in the cell was then gently warmed until it liquified. After the sample cooled back to room temperature, it resolidified with a smooth surface usable for spectroscopic studies.

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III. RESULTS AND DISCUSSION

Raman spectra of the v_1 (A'1) symmetric stretch mode of NO $_3$ occurring in 3.0, 7.0, 11, 13, and 15 M aqueous HAN solutions are shown in Figure 1. The spectral region displayed is about 900 to 1200 cm $^{-1}$ Stokes shifted from the laser excitation line. Both the v_1 (A'1) peak at 1048 cm $^{-1}$ and a N-OH vibration at 1010 cm $^{-1}$ can be observed in this region. Some of the characteristics of the spectra are listed in Table 1. On this scale, both peaks in Figure 1 appear symmetric for all the concentrations studied. The v_1 (A'1) peak position shifts to slightly higher frequencies as the HAN concentration is increased and the linewidth of this transition increases with increasing concentration. This finite linewidth, aside from the instrument function, physically corresponds to a situation where all the anions (NO $_3$) in solution do not have exactly the same environment giving rise to a vibrational frequency distribution around a mean frequency value. This environment can also change with time giving a fluctuating vibrational frequency. The environment surrounding the NO $_3$ changes from about eight water molecules per

ion at 3 M to about 0.3 water molecules per ion at 15 M. This change from largely ion-water interactions to anion-cation interactions is responsible for the frequency shift and broadening of the linewidth. Because of these changes in position and linewidth the "apparent" symmetric shape of the ν_1 (A'1) Raman mode could be the result of several symmetric peaks of slightly different mean frequency values where the amplitude of these peaks change as the environment around the NO_3 changes. Various cation-anion pairing entities have been assigned to deconvolutions of the Raman modes of NO_3 .

Table 1. Spectral Characteristics of the ν_1 (A¹) and ν_4 (E¹) $N0\bar{3}$ Vibrational Modes as a Function of Concentration for Aqueous HAN Solutions

Concentration Molar	v _l (A¦) Peak Position cm ⁻¹	V (A) Linewidth (FWHM)* cm ⁻¹	v _l (A¦) Integrated Intensity Arb.	v ₄ (E') Peak Position cm ⁻¹	v4 (E') Linewidth (FWHM)* cm ⁻¹	v ₄ (E') Integrated Intensity Arb.
3	1046.8	8.2	1.14	721.7	18.0	0.87
7	1047.1	9.5	2.63	723.3	19.0	2.17
11	1047.7	10.6	4.14	724.1	19.6	3.56
13	1048.0	11.0	4.87	725.0	20.3	4.25
15	1048.3	12.0	5.69	725.0	+	+
SOLID HAN	1047	<5		727.5	<11	·

Using published results as an analogy, some conclusions about aqueous HAN can be drawn. Literature data on spectral characteristics of some monovalent aqueous salts, together with this work for aqueous HAN, are contained in Table 2. It can be seen that all the alkali metal solutions listed 4,5,6 exhibit an increase in Raman frequency and linewidth with increasing concentration. This is true to a lesser extent with K^+ , but the saturation limits of K^+ in water prevented a proper comparison at higher concentration. From Table 2 it is seen that NH₃OH exhibits behavior similar to the alkali metal cations and not NH₄. One might first think that NH₄ is more like NH₃OH since both cations have the ability to form hydrogen bonds. However, Vollmar concluded from his studies that there is similar hydrogen bonding between NO₃ and either NH₄ or H₂O and thus, the environment, as seen by NO₃, is not changing as the solute concentration changes.

Many structures have been postulated from curve resolving the v_1 (A'_1) mode of NO_3 . For aqueous salt solutions, such as $NaNO_3$, which exhibit frequency and linewidth changes with changing concentration Frost and James have resolved the curves into four principal components. These are: a free aquated NO_3 at 1048 cm⁻¹, a solvent-separated-ion-pair at 1050 cm⁻¹, a contact-ion-pair at 1052 cm⁻¹ and larger ion aggregates at 1070 cm⁻¹. By expanding the frequency scale for the v_1 (A'₁) mode as shown in Figure 2, the peak frequency and linewidth differences between 3 and 13 M HAN solutions can

^{*}The spectral resolution is given as full width at half maximum.

⁺A large fluorescence signal obscured these results.

clearly be observed. A least squares procedure was used as an attempt to fit the 13 M curve with two symmetric curves, however, this did not provide any improvement over a single symmetric curve fit. It is still possible that the 13 M curve may be a sum of components, but the resolution of the data does not seem to warrant that type of analysis at this point.

Table 2. Comparison of the Spectral Characteristics of the v_1 (A'_1) Mode of NO $_3^-$ in Aqueous HAN With Published Results for Some Other Aqueous Monovalent Salt Solutions

Cation	Concentration Molar	v _l (A¦) Peak Position cm ⁻¹	ν ₁ (A¦) Linewidth cm ⁻¹	Refe	rences
Li ⁺	0.85	1048.45	11.68		
LI	8.51	1052.07	14.77		6
	0.40	1072.07	14.77		6
	10.0		18.1		7 7
	1.0	1048.2			/
		1051.9	Increases by ~70% over		,
	10.0	1051.9	this range		4
Na ⁺	0.70	1048.9	11.60		6
	7.04	1052.07	13.15		
	0.56		15.0		6 7 7
	7.00		15.8		7
	1.0	1048.4	Increased by ~40% over		
	8.0	1051.1	this range		4
K ⁺	0.26	1048.41	11,52		6
	2.58	1049.22	11.60		6
	0.5	1048.2	Increases by ~4% over		•
	2.75	1049.1	this range		4
NH <mark></mark> ∔	1.00	1048.0	11.56		6
4	9.98	1048.0	11.68		6
	1.00	1047.6	Essentially constant over		
	10.00	1047.8	this range		4
NН ₃ ОН ⁺	3.0	1046.8	8.2	This	Work
J	11	1047.7	10.6		Work
	15	1048.3	12.0		Work

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In much more dilute aqueous HAN solutions (about 140 water molecules per ion), it is found that solvation is preferred over ion-pairing. This result follows from analogy with the data of Janz. He demonstrated this behavior with AgNO3 dissolved in various mixtures of water and acetonitrile. With AgNO3 dissolved in water, the ν_1 (A1) band of NO3 exhibits one symmetric peak at $\sim 1046~\rm cm^{-1}$. When AgNO3 is dissolved in acetonitrile the ν_1 (A1) band becomes quite asymmetric and can be resolved into two symmetric peaks centered at 1041 and 1038 cm $^{-1}$. Dissolving AgNO3 into various mixtures of these solvents cause the relative proportions of these peaks to change. Janz assigns the 1041 cm $^{-1}$ peak to aquated or free NO3 and the 1038 cm $^{-1}$ peak to

contact-ion-pairs. In this work, we obtained the Raman spectrum of AgNO 3 dissolved in CH3CN and compared it with the spectra of HAN dissolved in H2O and then CH3CN. Figure 3 contains a comparison among: (a) ~0.2 M aqueous HAN, (b) ~0.2 M AgNO 3 dissolved in CH3CN, and (c) ~0.2 M HAN dissolved in CH3CN. From Table 1 the v_1 (A1) mode of NO 3 is found to occur at 1046.8 cm 1 for 3 M aqueous HAN. Using this frequency for 0.2 M aqueous HAN, values of 1036.5 and 1039.8 cm 1 are estimated for the double peaked band of Figure 3b. When HAN is dissolved in CH3CN, the v_1 (A1) band shifts to about the same position as AgNO 3 in CH3CN. The shapes of the bands, Figures 3b and 3c, are different, but both are distinctly asymmetric indicating multiple NO 3 entities. No ion-pairing behavior is exhibited for HAN or AgNO 3 with a H2O solvent. Consequently, we conclude that aquated ions are favored over ion-pairs with the highly polar water solvent which is in accord with Bjerrum's criteria. Nevertheless, the concentrations of interest, around 11 M for propellant applications, are such that there are insufficient water molecules for complete aquation.

Before leaving the symmetric stretch vibration of NO_3 , a contrast between 13 M aqueous HAN and solid HAN is made in Figure 4. Immediately apparent is the narrowing of the linewidth of the solid HAN vibrational modes. The linewidth decreases from 11 cm⁻¹ to values less than 5 cm⁻¹ when HAN solidifies. An apparent shift to lower frequencies also occurs upon solidification, see Table 1. Only approximate values for the solid data are given because they appeared time dependent. Experimental spectra were gathered on solid HAN over three consecutive days, and the linewidth was observed to narrow with time. Linewidths typically narrow substantially when changing from liquid to solid phase as the orientational dynamics are frozen out. This decrease in linewidth with time is speculated to be the solid changing from an amorphous to crystalline state. The laser excitation source provides some heating of the sample which could promote this process. More will be said about the solid in the discussion of the v_{L} (E') mode of NO_3 .

The degenerate in-plane bending mode of NO_3 has also been investigated for various concentrations and temperatures; these results are displayed in Figures 5 and 6, and Table 1. This v_{Δ} (E') mode is Raman_active only, and extensively referred to in the literature as a diagnostic' for the determination of contact-ion-pairing. Unfortunately, the data reported are of only fair-quality for the following reason. The ν_4 (E') mode is about a factor of ten weaker than the ν_1 (A'₁) mode which in itself does not cause difficulty. However a laser induced fluorescence impurity signal (to be discussed in more detail later) comprising about 50% of the total v_{i} (E') signal caused the signal-to-noise ratio for this Raman mode to be poor. Nonetheless, we can still distinctly see (Table 1) that both the linewidth and peak position increase with increasing HAN concentration, similar to the behavior of the v_1 (A₁) mode. With this quality of data, small asymmetries, indicative of any contact-ion-pairing, cannot be unambiguously determined. The type of behavior reported in the literature 7,8 for the ν_4 (E') band of $NO_3^$ is that a band around 717 cm $^{-1}$ occurs for either aquated NO $_3^{-4}$ or solvent-separated-ion-pairs and another band around 740 cm $^{-1}$ is reported to occur for contact-ion-pairing. Several Raman spectra for the v_4 (E') mode in 13 M aqueous HAN, see Figure 6, have been obtained over a temperature range from -50 to 22°C. The curve peaking at 725 cm⁻¹ is for room temperature (22°C) and this mode shifts to higher frequency as the temperature is decreased. An increase of 4.4 cm⁻¹ is observed for a temperature decrease of 72°C. The

-50°C curve appears somewhat asymmetric, however, it was felt that the data is not sufficiently precise to attempt a deconvolution. It is interesting to note that Bjerrum's contact-ion-pairing distance criteria increases with decreasing temperature, and the center frequency of the ν_4 (E') mode moves in the direction of the reported contact-ion-pair frequency as the temperature is decreased. Our results for this Raman mode are consistent with the presence of aquated ions, solvent-separated-ion-pairs, and a small amount of contact ion-pairing existing in the concentration range studied.

Dramatic time dependent changes were observed to occur in the ν_4 (E') Raman mode for the solid HAN that we produced. A Raman spectrum of 13 M HAN is contrasted with three spectra of solid HAN taken on three consecutive days after preparation, see Figure 7. Here again the linewidth decreases upon solidification, however, the frequency increases upon solidification contrary to the behavior of the ν_1 (A') mode. From day 1 to 3 the linewidth decreased and two or more bands appeared with center frequencies around 724 and 730 cm⁻¹. Fifer's Fourier transform infrared studies of solid HAN also show two NO_3 bands appearing at the same frequencies. Again the explanation offered for the time dependence is changing from an amorphous to a crystalline state.

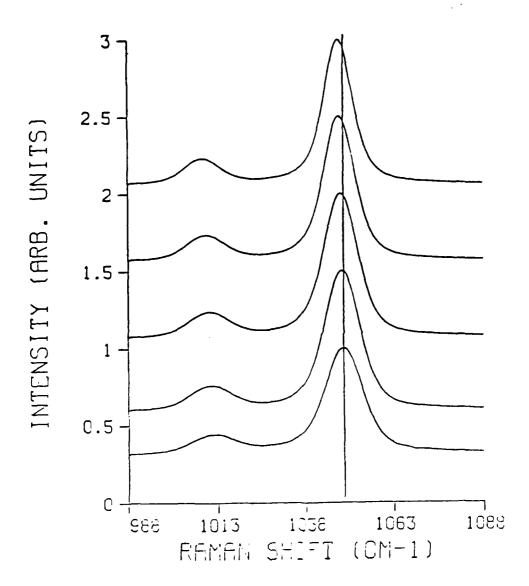
As a consistency check on the experimental data for the v_1 (A'₁) and v_4 (E') Raman bands, their integrated intensities were obtained as a function of concentration and the results are shown in Table 1 and plotted in Figure 8. The proper linear behavior is demonstrated and a straight line extrapolation of the v_1 (A'₁) data passes through the origin as required, however, the v_4 (E') extrapolation does not. Improper subtraction of the laser induced fluorescence impurity background is probably responsible for this variation.

This laser induced fluorescence background was observed to vary substantially for three different lots of aqueous HAN solutions studied, as can be observed in the low resolution Raman spectra of 13 M aqueous HAN shown in Figure 9. The fluorescence contribution, ranging from about 40% (bottom spectra) to over 90% of the total signal, can seriously impair spectroscopic probing. Several other tests have been performed to characterize the nature of this impurity. As seen by eye it is apparent that the degree of yellowing of the solution is proportional to the amount of impurity. Two absorption spectra, Figure 10, are shown for the 13 M aqueous HAN solutions that produced the bottom and top Raman spectra of Figure 9. The large absorption at wavelengths less than 350 nm is due to the nitrate ions, but in addition, there is a substantial broad structureless absorption extending to wavelengths beyond 550 nm, and this absorption must come from impurities. Since the absorption spectrum appeared structureless, tests for possible microbe contamination were performed. Microscope examination and culturing on several media, however, gave negative results. NO, has been suggested as a possible decomposition product which could be consistent with these observations. To date, experiments to detect trace amounts of this species have not been attempted. Any substantial amounts of NO2 should lead to rapid sample decomposition, and this is not observed. The yellowish samples exist for many months without appreciable decomposition.

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IV. SUMMARY

From Raman investigations on the nitrate anion existing in aqueous HAN solutions and a comparison with published results for other monovalent aqueous salt solutions, some general structural characteristics of aqueous HAN have been determined. In dilute HAN solutions, solvated ions are favored over contact-ion-pairs. This phenomena is observed, in general, for monovalent salts when the solvent has a large dielectric constant such as water. As the concentration of HAN is increased, complete solvation or aquation is no longer possible. At such concentrations, solvent-separated-ion-pairs and contaction-pairs can exist. The entities do not exist in isolation since the concentration of solute is such that there are other ions in the near vicinity. Because of the influence of many ions on each other, the Raman spectral perturbations can be less than for isolated contact-ion-pairs as one would have in systems where the solvent has a low dielectric constant. Lastly, an impurity causing laser induced fluorescence signals has been partially characterized. This impurity is not associated with any appreciable decomposition of the material; nonetheless, it can seriously degrade certain spectroscopic observations.



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Figure 1. Raman Spectra of the v_1 (A_1') Mode of NO_3^- Taken for 3, 7, 11, 13, and 15 M Aqueous HAN Solutions. The concentrations are displayed in order; 3 M being the top spectrum. The vertical line is drawn in to emphasize the frequency shift.

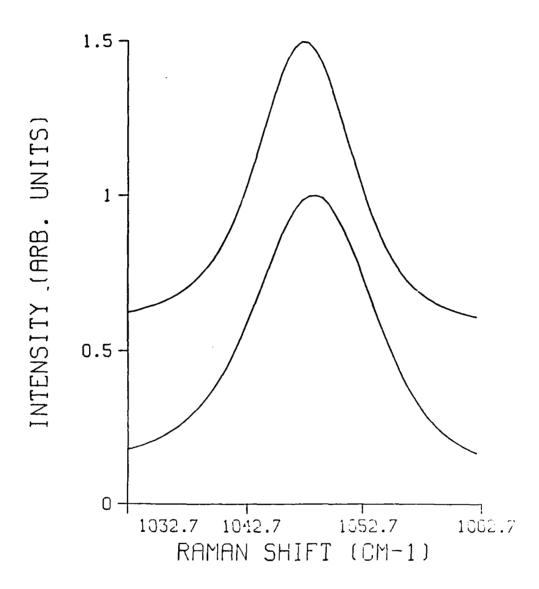


Figure 2. Raman Spectra of the v_1 (A1) Mode of NO_3 Taken for 3 and 13 M Aqueous HAN. The top spectrum is 3 M. The frequency scale has been expanded about threefold from that of Figure 1.

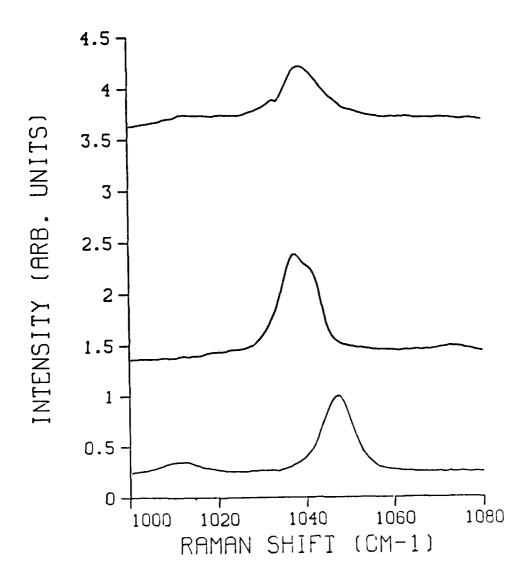


Figure 3. Raman Spectra of the v_1 (A1) Mode of NO_3 Taken for ~ 0.2 M HAN Dissolved in CH3CN (Top Spectrum), ~ 0.2 M AgNO3 Dissolved in CH3CN (Middle Spectrum), and ~ 0.2 M Aqueous HAN (Bottom Spectrum)

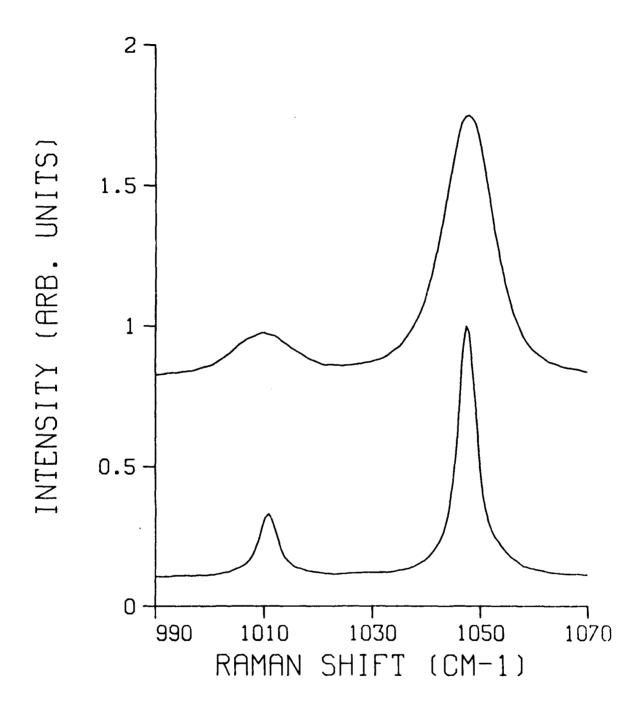


Figure 4. Raman Spectra of the v_1 (A1) Mode of NO $_3^-$ Taken for 13 M Aqueous HAN (Top Spectrum) and Solid HAN

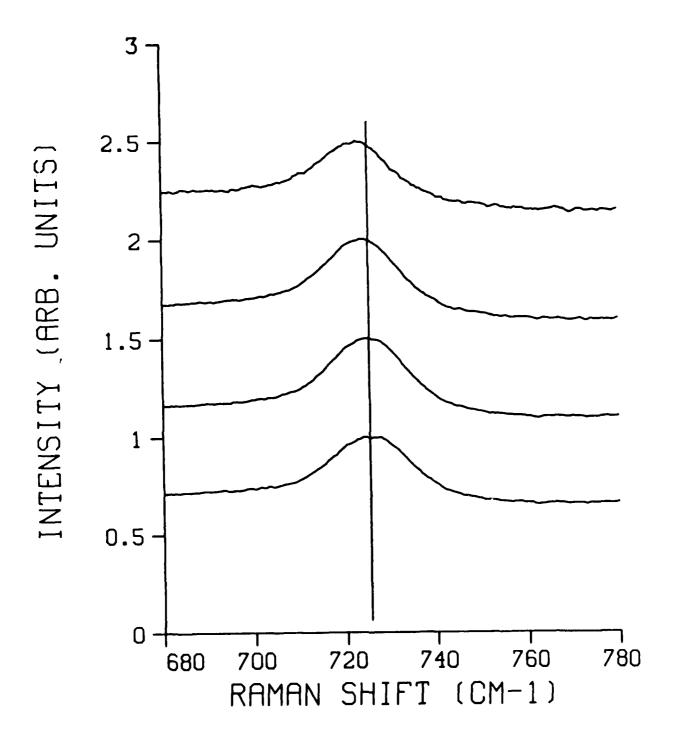


Figure 5. Raman Spectra of the v_4 (E') Mode of NO_3^- Taken for 3, 7, 11, and 13 M Aqueous HAN Solutions. The concentrations are displayed in order; 3 M being the top spectrum. The vertical line is drawn in to emphasize the frequency shift.

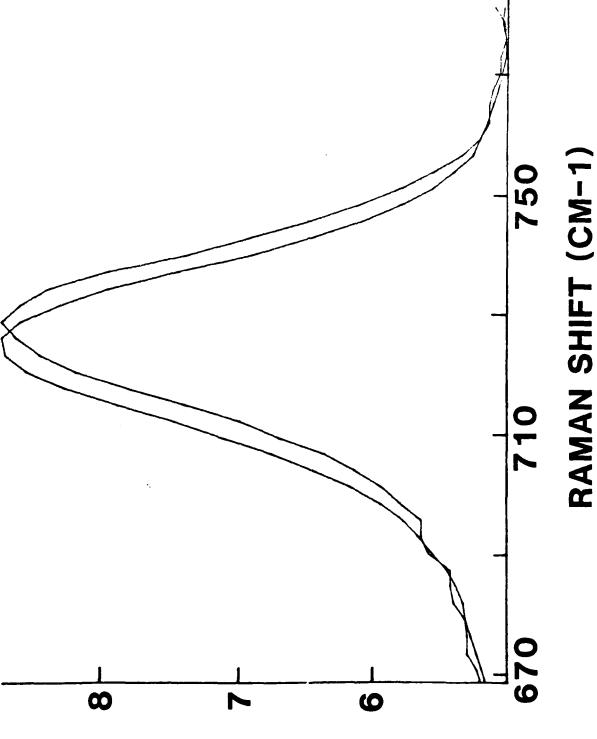


Figure 6. Raman Spectra of the λ_d (E') Mode of NO $_3$ Taken for 13 M Aqueous HAN. The spectrum to the left (lowest frequency peak) is for a temperature of 22°C; the other a temperature of -50°C.

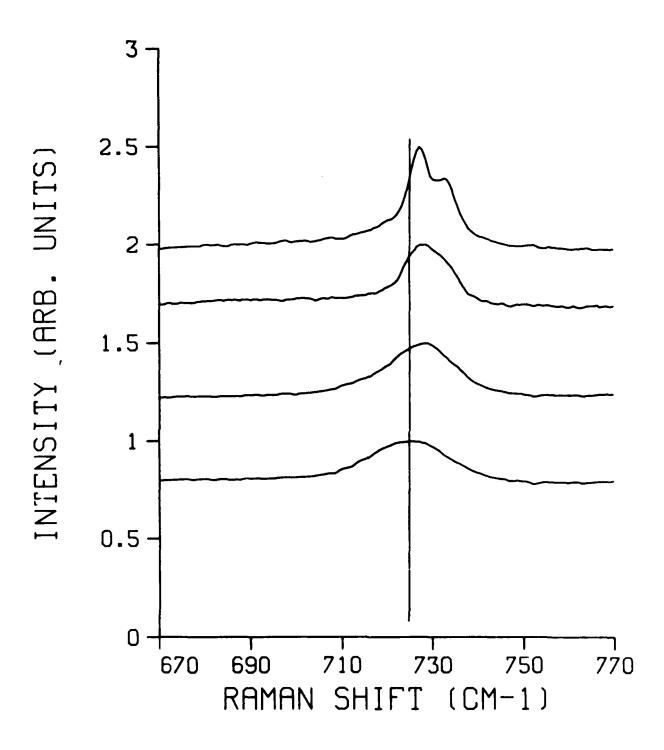
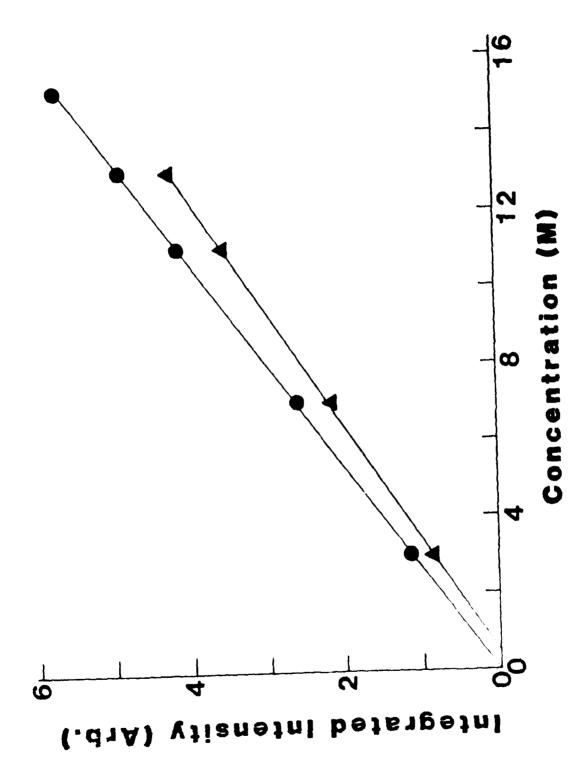


Figure 7. Raman Spectra of the v_4 (E') Mode of NO_3^- Taken for 13 M Aqueous HAN (Bottom Spectrum), Solid HAN on Day 1 (Next Spectrum), Solid HAN on Day 2 (Next Spectrum), and Solid HAN on Day 3 (Top Spectrum). The vertical line is drawn in to emphasize the frequency shift.



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Figure 8. Integrated intensity of Two NO $_3$ Raman Bands in Aqueous HAN Plotted as a Function of Cone ntration. The circles represent data for the ν_1 (A $_1$) mode and the triangles are data for the ν_4 (E) mode.

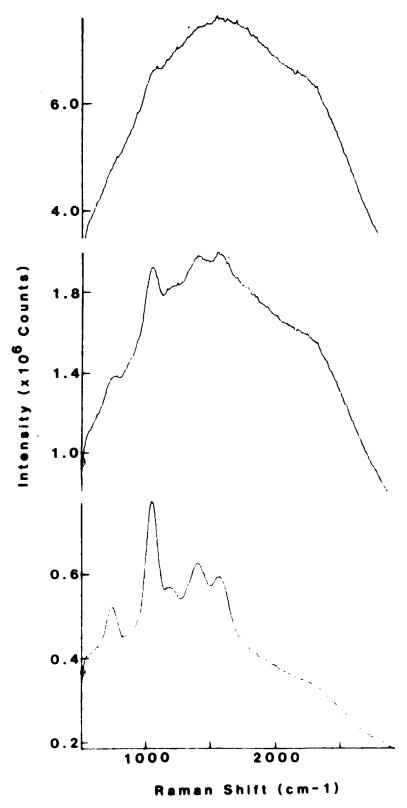


Figure 9. Raman Spectra for 13 M Aqueous HAN Solutions Showing the Effect of a Fluorescence Impurity. Maximum impurity is in the topspectrum, decreasing downward.

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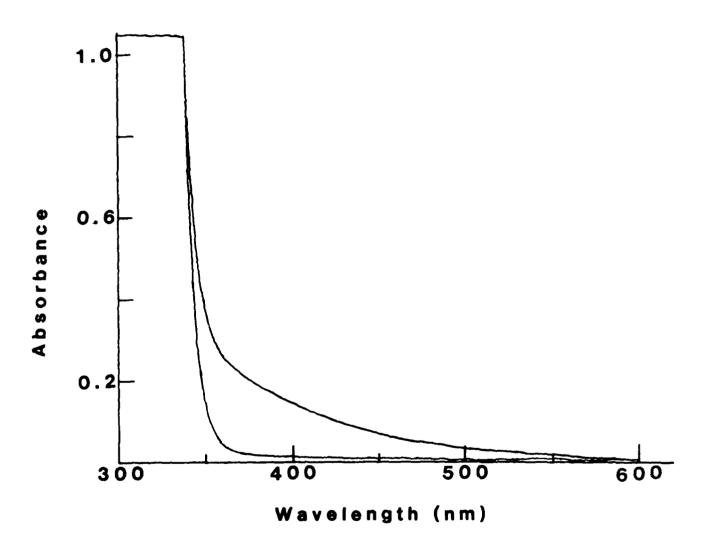


Figure 10. Absorption Spectra for Two 13 M Aqueous HAN Solutions with Differing Amounts of Fluorescence Impurity

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